

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

ECH8411— General-Purpose Switching Device Applications

Features

- · Ultrahigh-speed switching.
- · 1.8V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		9	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	36	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	1.4	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.5		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	7	12		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	ID=4A, VGS=4V		12	16	mΩ
	R _{DS} (on)2	I _D =2A, V _G S=2.5V		16	23	mΩ
	RDS(on)3	ID=2A, VGS=1.8V		25	36	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		1740		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		310		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		290		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		30		ns
Rise Time	tr	See specified Test Circuit.		170		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		240		ns
Fall Time	tf	See specified Test Circuit.		210		ns

Marking: KR Continued on next page.

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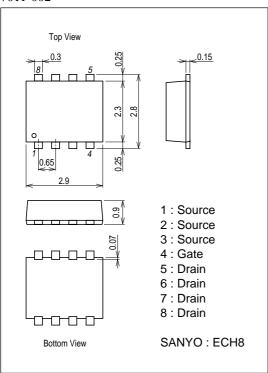
ECH8411

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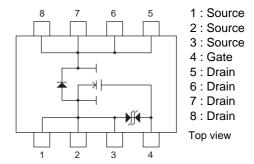
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Oill
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =9A		21		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =9A		3.5		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =9A		6.2		nC
Diode Forward Voltage	VSD	IS=9A, VGS=0V		0.84	1.2	V

Package Dimensions

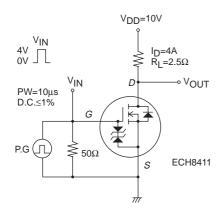
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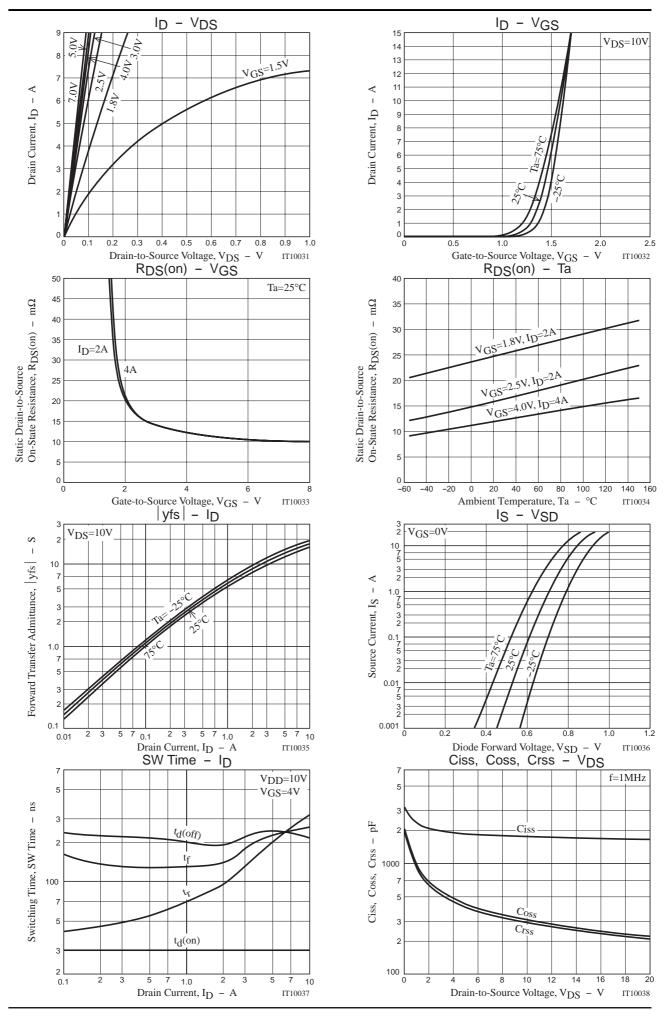


Electrical Connection

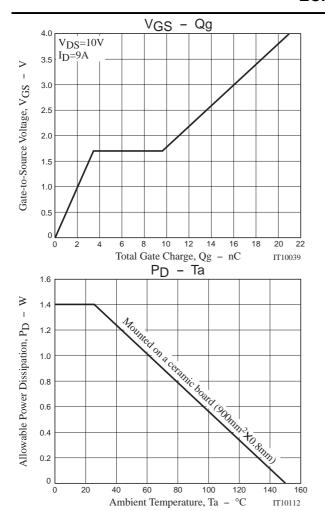


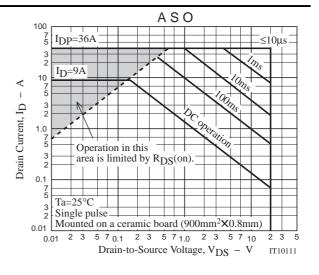
Switching Time Test Circuit





ECH8411





Note on usage: Since the ECH8411 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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